

EMRB82B-32.768K

[Click part number to visit Part Number Details page](#)

REGULATORY COMPLIANCE (Data Sheet downloaded on May 20, 2017)


[Click badges to download compliance docs](#)

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ITEM DESCRIPTION

MEMS Clock Oscillators LVCMOS (CMOS) 2.5Vdc 4 Pad 0.8mm x 1.5mm Chip Scale Package (CSP) 32.768KHz ± 75 ppm over -10°C to +70°C

ELECTRICAL SPECIFICATIONS

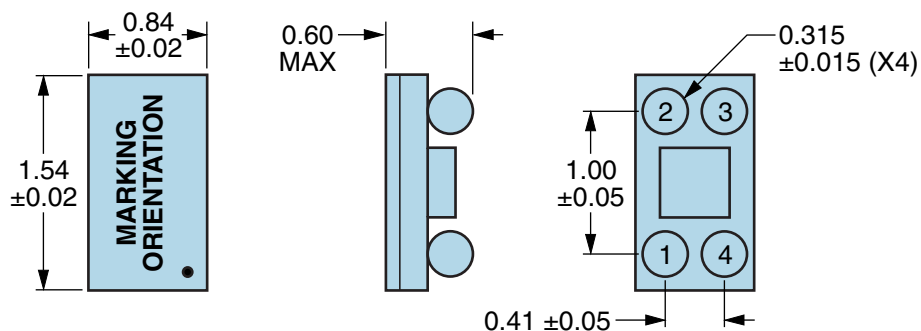
Nominal Frequency	32.768KHz
Frequency Tolerance/Stability	± 75 ppm Maximum over -10°C to +70°C (Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, and Output Load Change)
Frequency Tolerance	± 20 ppm Maximum (Measured at 25°C ± 2 °C, at Vdd=2.5Vdc, Post Reflow, with board level underfill)
Aging at 25°C	± 1 ppm Maximum First Year
Supply Voltage	2.5Vdc $\pm 10\%$
Core Operating Current	0.9 μ A Typical (at 25°C), 1.3 μ A Maximum
Output Stage Operating Current	0.065 μ A/Vpp Typical, 0.125 μ A/Vpp Maximum
Input Current	1.1 μ A Typical (at 25°C), 1.6 μ A Maximum (No Load, Nominal Vdd)
Output Voltage Logic High (Voh)	90% of Vdd Minimum (IOH = -10 μ A)
Output Voltage Logic Low (Vol)	10% of Vdd Maximum (IOL = +10 μ A)
Rise/Fall Time	100nSec Typical, 200nSec Maximum (Measured from 10% to 90% of waveform)
Duty Cycle	50 ± 2 (%) (Measured at 50% of waveform)
Load Drive Capability	15pF Maximum
Output Logic Type	CMOS
Period Jitter (RMS)	35nSec Typical (Measured at 25°C)
Power Supply Ramp	100mSec Maximum (Measured at 0Vdc to 90% of Vdd)
Start Up Time	180mSec Typical, 300mSec Maximum (at 25°C) 450mSec Maximum (over Operating Temperature Range) (Measured at Nominal Vdd)
Storage Temperature Range	-55°C to +125°C

ENVIRONMENTAL & MECHANICAL SPECIFICATIONS

ESD Susceptibility	JESD22-A114, HBM, 3000V
Flammability	UL94-V0
Mechanical Shock	MIL-STD-883, Method 2002, Condition E, 10,000G
Moisture Sensitivity	J-STD-020, MSL 1
Solderability	MIL-STD-883, Method 2003
Temperature Cycling	JESD22-A104, Condition G
Vibration	MIL-STD-883, Method 2007, Condition C, 70G

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MECHANICAL DIMENSIONS (all dimensions in millimeters)

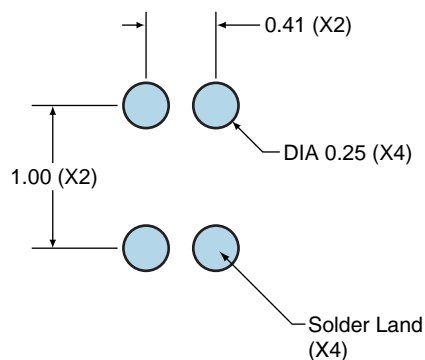


PIN	CONNECTION
1	Ground
2	Output
3	Supply Voltage
4	Ground

LINE	MARKING
1	XX XX=Ecliptek Manufacturing Identifier
2	XXX XXX=Ecliptek Manufacturing Identifier (continued)

Suggested Solder Pad Layout

All Dimensions in Millimeters



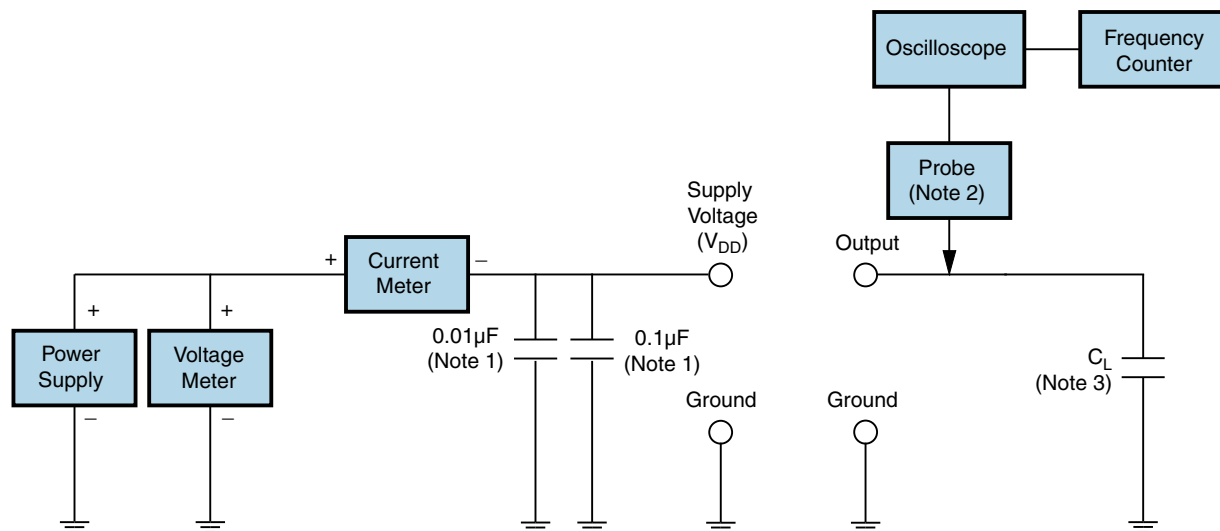
All Tolerances are ± 0.1

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OUTPUT WAVEFORM



Test Circuit for CMOS Output



Note 1: An external 0.01 μ F ceramic bypass capacitor in parallel with a 0.1 μ F high frequency ceramic bypass capacitor close (less than 2mm) to the package ground and supply voltage pin is recommended.

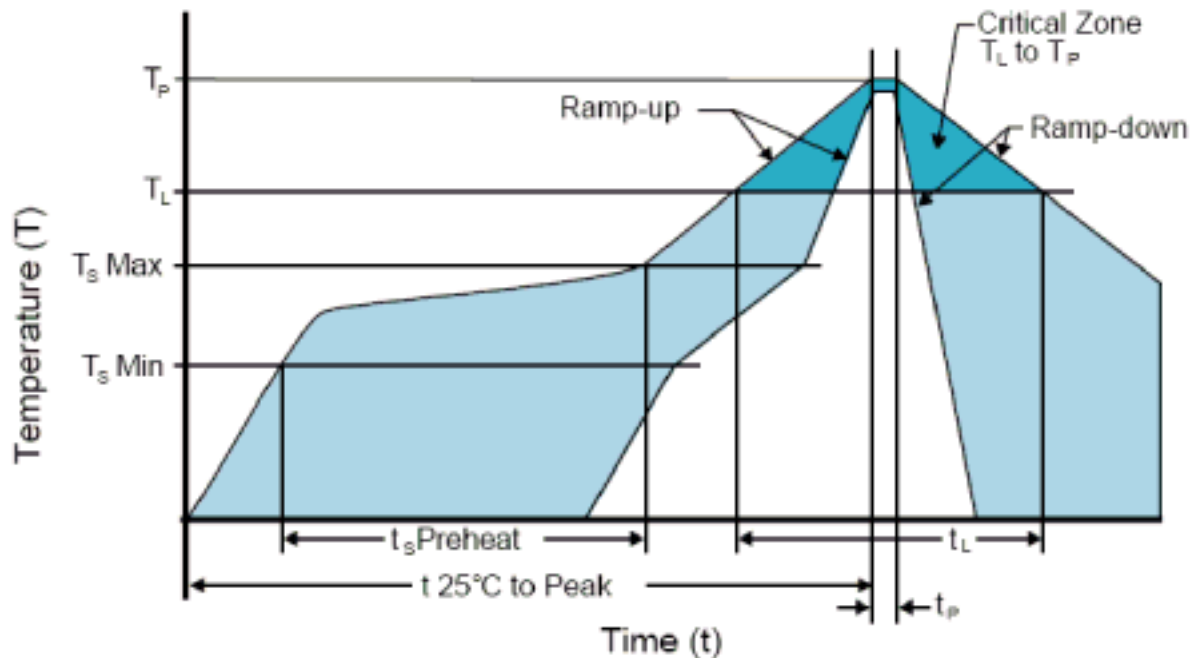
Note 2: A low input capacitance (<12pF), 10X Attenuation Factor, High Impedance (>10Mohms), and High bandwidth (>300MHz) passive probe is recommended.

Note 3: Capacitance value C_L includes sum of all probe and fixture capacitance. See applicable specification sheet for 'Load Drive Capability'.

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Recommended Solder Reflow Methods



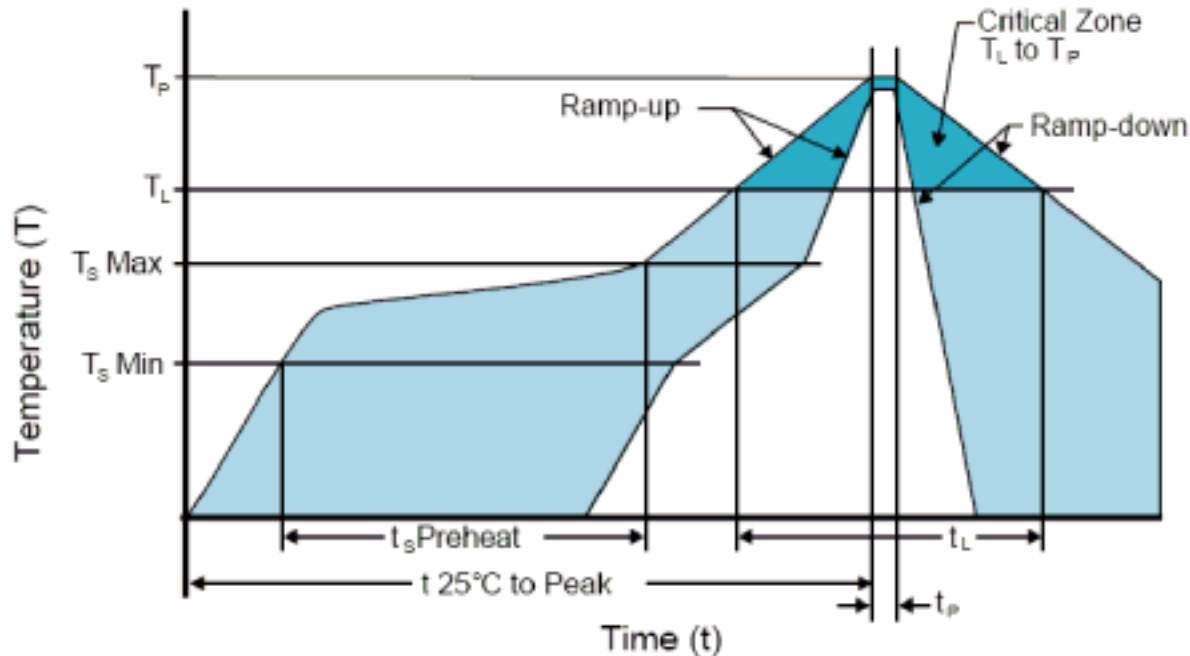
High Temperature Infrared/Convection

$T_S \text{ MAX}$ to T_L (Ramp-up Rate)	3°C/Second Maximum
Preheat	
- Temperature Minimum ($T_S \text{ MIN}$)	150°C
- Temperature Typical ($T_S \text{ TYP}$)	175°C
- Temperature Maximum ($T_S \text{ MAX}$)	200°C
- Time ($t_s \text{ MIN}$)	60 - 180 Seconds
Ramp-up Rate (T_L to T_P)	3°C/Second Maximum
Time Maintained Above:	
- Temperature (T_L)	217°C
- Time (t_L)	60 - 150 Seconds
Peak Temperature (T_P)	260°C Maximum for 10 Seconds Maximum
Target Peak Temperature ($T_P \text{ Target}$)	250°C +0/-5°C
Time within 5°C of actual peak (t_p)	20 - 40 Seconds
Ramp-down Rate	6°C/Second Maximum
Time 25°C to Peak Temperature (t)	8 Minutes Maximum
Moisture Sensitivity Level	Level 1
Additional Notes	Temperature shown are applied to body of device.

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Recommended Solder Reflow Methods



Low Temperature Infrared/Convection 240°C

Ts MAX to TL (Ramp-up Rate)	5°C/Second Maximum
Preheat	
- Temperature Minimum (Ts MIN)	N/A
- Temperature Typical (Ts TYP)	150°C
- Temperature Maximum (Ts MAX)	N/A
- Time (ts MIN)	60 - 120 Seconds
Ramp-up Rate (TL to TP)	5°C/Second Maximum
Time Maintained Above:	
- Temperature (TL)	150°C
- Time (tL)	200 Seconds Maximum
Peak Temperature (TP)	240°C Maximum
Target Peak Temperature (TP Target)	240°C Maximum 2 Times / 230°C Maximum 1 Time
Time within 5°C of actual peak (tp)	10 Seconds Maximum 2 Times / 80 Seconds Maximum 1 Time
Ramp-down Rate	5°C/Second Maximum
Time 25°C to Peak Temperature (t)	N/A
Moisture Sensitivity Level	Level 1
Additional Notes	Temperature shown are applied to body of device.

Low Temperature Manual Soldering

185°C Maximum for 10 Seconds Maximum, 2 times Maximum. (Temperature shown are applied to body of device.)

High Temperature Manual Soldering

260°C Maximum for 5 Seconds Maximum, 2 times Maximum. (Temperature shown are applied to body of device.)